

SCDS306-OCTOBER 2010

USB 2.0 High-Speed (480 Mbps) and Audio Switches with Negative Signal Capability and 1.8-V Logic Compatibility

Check for Samples: TS5USBA224

FEATURES

- High-Speed USB Switch:
 - $-4\Omega R_{DSON}$ Typical
 - 12.5 pF C_{ON} Typical
 - 650-MHz Bandwidth (-3 dB)
- Audio Switch:
 - 3 Ω R_{DSON} Typical
 - Negative Rail Capability
 - Low THD: <0.05%
 - Internal Shunt Resistors for Click-and-Pop Reduction
 - Powered From V_{AUDIO} (2.7V to 5.5V)
- 1.8-V Compatible Control Input (A_{SEL} and V_{BUS}) Threshold
- I_{OFF} Supports Partial Powerdown Mode
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
 - 200-V Machine Model (A115-A)

DESCRIPTION

The TS5USBA224 is a double-pole, double throw (DPDT) multiplexer that includes a low-distortion audio switch and a USB 2.0 High-Speed (480Mbps) switch in the same package. This configuration allows the system designer to use a common connector for audio and USB data. The audio switch is designed to allow audio signals to swing below ground which makes this common connector configuration possible.

The TS5USBA224 is powered up using V_{AUDIO}. When A_{SEL}=High, the audio path is selected regardless of the logic level at V_{BUS}. If A_{SEL}=Low and V_{BUS}=High, the USB path is selected. Otherwise if A_{SEL}=Low and V_{BUS}=Low, the audio path is selected.

The TS5USBA224 also features shunt resistors on the audio path to reduce clicks and pops that may be heard when the audio switches are selected.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾ ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN 0.4-MM PITCH – RSW (Pb-Free)	Tape and reel	TS5USBA224RSWR	A5R

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.



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APPLICATIONS

- Cellular Phones
- Personal Digital Assistants (PDAs)
- Portable Instrumentation
- Digital Still Cameras
- Portable Navigation Devices



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

SUMMARY OF TYPICAL CHARACTERISTICS

	USB PATH	AUDIO PATH
Number of switches	2	2
ON-state resistance (r _{on})	4 Ω	3 Ω
ON-state resistance match (Δr_{on})	< 0.3 Ω	< 0.3 Ω
ON-state resistance flatness (r _{on(flat)})	N/A	1.5 Ω
Turn-on/turn-off time (t _{ON} /t _{OFF})	< 2 µs	< 4 µs
Bandwidth (BW)	650 MHz	N/A
OFF isolation (O _{ISO})	–22 dB	–83 dB
Crosstalk (X _{TALK})	–31 dB	–83 dB
Total harmonic distortion (THD)	N/A	0.05%

	PIN		DESCRIPTION
NO.	NAME	TYPE	DESCRIPTION
1	D-	I/O	USB Data (Differential –)
2	R	I/O	Right Channel Audio
3	L	I/O	Left Channel Audio
4	GND	Ground	Ground
5	V _{AUDIO}	Power	Supply Voltage
6	D–/L	I/O	USB/Audio Common Connector
7	D+/R	I/O	USB/Audio Common Connector
8	A _{SEL}	Input	Control Input for Audio Path
9	V _{BUS}	Input	Control Input for USB Path
10	D+	I/O	USB Data (Differential +)

PIN DESCRIPTION TABLE

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FONCTION TABLE									
A _{SEL}	V _{AUDIO}	V _{BUS}	L,R	D+, D–					
L	L	L	OFF	OFF					
L	L	Н	OFF	OFF					
L	Н	L	ON	OFF					
L	Н	Н	OFF ⁽¹⁾	ON					
Н	L	L	OFF	OFF					
Н	L	Н	OFF	OFF					
Н	Н	L	ON	OFF					
Н	Н	Н	ON	OFF					

FUNCTION TABLE

(1) 100Ω shunt resistors are enabled in this state.

TYPICAL APPLICATION BLOCK DIAGRAM



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ABSOLUTE MAXIMUM RATINGS⁽¹⁾⁽²⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{AUDIO}	Supply voltage range ⁽³⁾		-0.5	6.5	V
V _{D+} V _{D-}	Analog voltage Renge (3)		-0.5	6.5	V
V _R V _L	Analog voltage Kange	V _{AUDIO} – 6.5	V _{AUDIO} + 0.5	V	
Ι _κ	Analog port diode current	$V_{D+}, V_{D-} < 0$	-50		mA
I _{D+} , I _{D-} I _R , I _L	ON-state switch current	V_{D+}, V_{D-} = 0 to $V_{AUDIO},$ $V_{R}, V_{L} V_{D+/R}, V_{D-/L}$ = V_{AUDIO} – 5.5 V to V_{AUDIO}	-100	100	mA
I _{D+/R} I _{D–/L}	ON-state peak switch current ⁽⁴⁾		-200	200	
VI	Digital input voltage range		-0.5	6.5	V
I _{IK}	Digital logic input clamp current ⁽³⁾	V ₁ < 0		-50	mA
I _{AUDIO}	Continuous current through V _{AUDIO}			100	mA
I _{GND}	Continuous current through GND		-100		mA
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(3) All voltages are with respect to ground, unless otherwise specified.

(4) Pulse at 1-ms duration <10% duty cycle.

PACKAGE THERMAL IMPEDANCE⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

PARAMETER				TEST CONDITIONS	ТҮР	UNIT		
θ_{JA}	P	Package thern	nal impedance		RSW pack	age	175	°C/W

(1) The package thermal impedance is calculated in accordance with JESD 51-7.

ELECTRICAL CHARACTERISTICS

 $T_A = -40^{\circ}$ C to 85°C, typical values are at $V_{AUDIO} = 3.3$ V, $T_A = 25^{\circ}$ C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
USB SWITCH	l						
V_{D+}, V_{D-}	Analog voltage range			0		5.5	V
r _{on}	ON-state resistance	$V_{AUDIO} = 3 V, V_{BUS} = 5 V, V_{ASEL} = 0 V, V_{D+/D-} = 0 V, 0.4 V, I_{ON} = -8 mA$	Switch ON		4	7	Ω
Δr_{on}	ON-state resistance match between channels		Switch ON			0.3	Ω
I _{D+(OFF)} I _{D–(OFF)}	D+ ,D- OFF leakage current		Switch OFF			±50	nA
I _{D+(ON)} I _{D-(ON)}	D+ ,D– ON leakage current	$V_{AUDIO} = 3.6 V, V_{BUS} = 5 V, V_{ASEL} = 0$ V, $V_{D+}, V_{D-} = 0.3 V, V_{D+/R} = Open$	Switch ON			±50	nA
AUDIO SWIT	СН						
V_R, V_L	Analog voltage range			V _{AUDIO} – 5.5		V _{AUDIO}	V
r _{on}	ON-state resistance	$V_{AUDIO} = 3 V, V_{BUS} = 0 V, V_{ASEL} = 3 V, V_{L/R} = -2 V, 0 V, 0.7 V, I_{ON} = -26 mA$	Switch ON		3	5	Ω
Δr_{on}	ON-state resistance match between channels	$\label{eq:VAUDIO} \begin{array}{l} V_{AUDIO} = 3 \ V, \ V_{BUS} = 0 \ V, \ V_{ASEL} = 3 \ V, \\ V_{L/R} = 0.7 \ V, \ I_{ON} = -26 \ mA \end{array}$	Switch ON			0.3	Ω
r _{on (flat)}	ON-state resistance flatness		Switch ON		1.5	2.5	Ω

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ELECTRICAL CHARACTERISTICS (continued)

 $T_A = -40^{\circ}C$ to 85°C, typical values are at $V_{AUDIO} = 3.3$ V, $T_A = 25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
r _{SHUNT}	Shunt resistance		Switch OFF		100	200	Ω
I _{L(OFF)} I _{R(OFF)}	L, R OFF leakage current		Switch OFF			±50	nA
I _{L(ON)} I _{R(ON)}	L, R ON leakage current		Switch ON			±50	nA
DIGITAL (CONTROL INPUTS (A _{SEL} , V _{BUS})						
V _{IH}	Input logic high	$V_{AUDIO} = 2.7V$ to 5.5V		1.2			V
V _{IL}	Input logic low	$V_{AUDIO} = 2.7V$ to 5.5V				0.5	V
I _{IN}	Input leakage current	V _{AUDIO} = 3.6V	VIN = 3.6V			±10	μA
			VIN = 0V			±1	
r _{PD1}	Internal pulldown resistance				3		MΩ
r _{PD2}	Internal pulldown resistance				5		MΩ

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DYNAMIC CHARACTERISTICS

 $T_A = -40^{\circ}$ C to 85°C, typical values are at $V_{AUDIO} = 3.3$ V, $T_A = 25^{\circ}$ C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT	
USB SWIT	СН					
t _{ON}	Turn-on time	$\label{eq:VAUDIO} \begin{split} V_{AUDIO} &= 3 \ V, \ V_{BUS} = 0 \ V \ to \ 5 \ V, \ V_{ASEL} = 0 \ V, \\ V_{D+/R, \ D-/L} &= 1 \ V, \ Figure \ 10 \end{split}$		2		μS
t _{OFF}	Turn-off time	$ V_{AUDIO} = 3 \text{ V}, V_{BUS} = 5 \text{ V to } 0 \text{ V}, V_{ASEL} = 0 \text{ V}, $ $ V_{D+/R, D-/L} = 1 \text{ V}, Figure 10 $		1		μs
t _{SK(O)}	Channel-to-channel skew	f = 240 MHz, Figure 11		35		ps
t _{SK(P)}	Skew of opposite transitions of same output	f = t 240 MHz, Figure 11	25		ps	
$\begin{array}{c} C_{D+(OFF)} \\ C_{D-(OFF)} \end{array}$	D+, D-OFF capacitance	$V_{AUDIO} = 3 V$, $V_{BUS} = 0 V$, $A_{SEL} = 3 V$, f = 240 MHz	2.8		pF	
C _{D+(ON)} C _{D-(ON)}	D+, D– ON capacitance	$V_{AUDIO} = 3 V$, $V_{BUS} = 5 V$, $A_{SEL} = 0 V$, f = 240 MHz	Switch ON	12.5		pF
CI	Digital input capacitance	$V_{AUDIO} = 3 V$, $V_{BUS} = 0 V$, $A_{SEL} = 0 V$, f = 1 MHz	2.2		pF	
BW	Bandwidth	$V_{AUDIO} = 3 \text{ V}, V_{BUS} = 5 \text{ V}, V_{ASEL} = 0 \text{ V}, Figure 12$	Switch ON	650		MHz
O _{ISO}	OFF Isolation		-22		dB	
X _{TALK}	Crosstalk	$\label{eq:VAUDIO} \begin{array}{l} V_{AUDIO} = 3 \; V, \; V_{BUS} = 5 \; V, \; V_{ASEL} = 0 \; V, \\ R_{L} = 50 \; \Omega, \; f = 240 \; MHz, \; Figure \; 13 \end{array}$	Switch ON	-31		dB
AUDIO SW	ІТСН					
t _{ON}	Turn-on time	$V_{AUDIO} = 3 V$, $V_{BUS} = 0 V$ or 5 V, $V_{ASEL} = 0 V$ to 3 V, $V_{D+/R,D-/L} = 1 V$, Figure 10		4		μS
t _{OFF}	Turn-off time	$V_{AUDIO} = 3 V$, $V_{BUS} = 0 V$, $V_{ASEL} = 3 V$ to 0 V, $V_{D+/R,D-/L} = 1 V$, Figure 10		1		μs
$\begin{array}{c} C_{L(OFF)} \\ C_{R(OFF)} \end{array}$	L , R OFF capacitance	$V_{AUDIO} = 3 V, V_{BUS} = 5 V, V_{ASEL} = 0 V,$ f = 20 kHz	Switch OFF	4.5		pF
C _{L(ON)} C _{R(ON)}	L, R ON capacitance	$V_{AUDIO} = 3 V$, $V_{BUS} = 0 V$, $V_{ASEL} = 3 V$, f = 20 kHz	Switch ON	15		pF
O _{ISO}	OFF Isolation		Switch OFF	-83		dB
X _{TALK}	Crosstalk		-83		dB	
THD	Total harmonic distortion	V_{AUDIO} = 3 V, V_{BUS} = 0 V, V_{ASEL} = 3 V, f = 20 Hz to 2 R_L = 600 \Omega, V_{IN} = 2 Vpp	0.05		%	
SUPPLY						
V _{AUDIO}	Power supply voltage			2.7	5.5	V
I _{AUDIO}	Positive supply current	$V_{AUDIO} = 3.6$ V, $V_{BUS} = 0$ or 5 V, $V_{ASEL} = 0$ to 3.6 V,	I _{OUT} = 0	6	10	μΑ
I _{OFF}	Power off leakage current	$V_{AUDIO} = 0 \text{ V}, V_{D+/R, D-/L, D+, D-, L, R} = 0 \text{ to } 5.5 \text{ V}$			±10	μΑ

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Figure 3. THD vs Frequency for Audio Switch

Figure 4. Gain vs Frequency for USB Switch

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Figure 5. Off Isolation vs Frequency for Audio Switch



Figure 7. Cross Talk vs Frequency for Audio Switch







Figure 8. Cross Talk vs Frequency for USB Switch

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TYPICAL CHARACTERISTICS (continued)



Figure 9. USB 2.0 Eye Pattern for USB Switch



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PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



TEST	$V_{AUDIO}(V_{DD})$	S1	RL	V _{in}	CL	V_{Δ}
t _{PLZ} /t _{PZL}	3.3 V	$2 \cdot \mathbf{V}_{DD}$	200 Ω	GND	10 pF	0.3 V
t _{PHZ} /t _{PZH}	3.3 V	GND	200 Ω	V _{DD}	10 pF	0.3 V



ENABLE AND DISABLE TIMES

- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r \leq 2.5 ns, t_r \leq 2.5 ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} or t_{OFF} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} or t_{ON} .

Figure 10. Test Circuit and Voltage Waveforms

STRUMENTS

XAS

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PARAMETER MEASUREMENT INFORMATION (Skew)



TEST	V _{AUDIO} (V _{DD})	S1	RL	V _{in}	CL
t _{sk(o)}	$\textbf{3.3 V} \pm \textbf{0.3 V}$	Open	200 Ω	V_{DD} or GND	10 pF
t _{sk(p)}	3.3 V \pm 0.3 V	Open	200 Ω	V _{DD} or GND	10 pF



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns.

D. The outputs are measured one at a time, with one transition per measurement.

Figure 11. Test Circuit and Voltage Waveforms

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PARAMETER MEASUREMENT INFORMATION



A. C_L includes probe and jig capacitance.

Figure 12. Test Circuit for Frequency Response (BW)

Frequency response is measured at the output of the ON channel. For example, when $V_{SEL} = 0$ and A_0 is the input, the output is measured at $0B_1$. All unused analog I/O ports are left open.

HP8753ES Setup

Average = 4 RBW = 3 kHz V_{BIAS} = 0.35 V ST = 2 s P1 = 0 dBM

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PARAMETER MEASUREMENT INFORMATION (continued)

- A. C_L includes probe and jig capacitance.
- B. A 50- Ω termination resistor is needed to match the loading of the network analyzer.

Figure 13. Test Circuit for Crosstalk (X_{TALK})

Crosstalk is measured at the output of the nonadjacent ON channel. For example, when $V_{SEL} = 0$ and A_1 is the input, the output is measured at A_3 . All unused analog input (A) ports are connected to GND, and output (B) ports are left open.

HP8753ES Setup

Average = 4 RBW = 3 kHz $V_{BIAS} = 0.35 V$ ST = 2 s P1 = 0 dBM





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A. C_L includes probe and jig capacitance.

B. A 50- Ω termination resistor is needed to match the loading of the network analyzer.

Figure 14. Test Circuit for OFF Isolation (O_{ISO})

OFF isolation is measured at the output of the OFF channel. For example, when $V_{SEL} = GND$ and A_1 is the input, the output is measured at 1B₂. All unused analog input (A) ports are connected to ground, and output (B) ports are left open.

HP8753ES Setup

Average = 4 RBW = 3 kHz $V_{BIAS} = 0.35 V$ ST = 2 s P1 = 0 dBM



20-May-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
TS5USBA224RSWR	ACTIVE	UQFN	RSW	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	A5R	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

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TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal	

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5USBA224RSWR	UQFN	RSW	10	3000	180.0	8.4	1.59	2.09	0.72	4.0	8.0	Q1

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PACKAGE MATERIALS INFORMATION

31-Mar-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5USBA224RSWR	UQFN	RSW	10	3000	202.0	201.0	28.0

MECHANICAL DATA



This package complies to JEDEC MO-288 variation UDEE, except minimum package height.



RSW (R-PUQFN-N10)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- E. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



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